NSN 5961-00-078-9592

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Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-078-9592 **Inclosure Material:** Glass **Overall Length:** 0.600 inches **Terminal Length:** 1.300 inches **Overall Diameter:** 0.081 inches **Internal Configuration:** Junction contact **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 50.0 collector to emitter voltage/static/base open and 6.0 breakdown voltage, collector to emitter, sustained **Current Rating Per Characteristic:** 100.00 microamperes source cutoff current **Power Rating Per Characteristic:** 50.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No